BLF9G38-10G

Power LDMOS transistor

AMPLEON

Rev. 1 — 19 October 2017

Product data sheet

1. Product profile

1.1 General description

10 W LDMOS power transistor for base station applications at frequencies from 3400 MHz to 3600 MHz.

Table 1. Typical performance

RF performance at T_{case} = 25 $^{\circ}$ C in a common source class-AB production test circuit.

Test signal	f	I _{Dq}	V _{DS}	$P_{L(AV)}$	G_p	ησ	ACPR _{5M}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	3400 to 3600	70	28	2	17.7	26	-30 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

1.2 Features and benefits

- High efficiency
- Integrated ESD protection
- Excellent ruggedness
- Excellent thermal stability
- Designed for broadband operation
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 3400 MHz to 3600 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		1 ,
3	source [1]		2 3 3 sym112

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package)	
	Name	Description	Version
BLF9G38-10G	-	earless flanged ceramic package; 2 leads	SOT975C

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 2 W (CW)	4.5	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C per section; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.11 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 10.5 \text{ mA}$	1.5	2	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	2.2	-	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 0.53 \text{ A}$	0.91	-	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 368 \text{ mA}$	561	-	2153	mΩ

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; f_1 = 3402.5 MHz; f_2 = 3407.5 MHz; f_3 = 3592.5 MHz; f_4 = 3597.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 70 mA; T_{case} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 2 W$	16.5	17.7	-	dB
RLin	input return loss	P _{L(AV)} = 2 W	-	-10	-6	dB
η_{D}	drain efficiency	P _{L(AV)} = 2 W	21	26	-	%
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 2 W	-	-30	-25	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLF9G38-10G is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 70 mA; P_{L} = 10 W (CW); f = 3400 MHz.

7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data of device; I_{Dq} = 70 mA (main); V_{DS} = 28 V; pulsed CW (t_p = 100 μ s: δ = 10 %).

f	Z _S [1]	Z _L [1]	P _L [2]	η _D [2]	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum	power load				'
3300	11.1 – j22.0	9.9 – j6.7	14.8	56.8	15.4
3400	15.0 – j19.0	8.7 – j8.4	14.6	57.1	15.6
3500	15.2 – j13.0	7.9 – j8.8	15.0	60.4	15.9
3600	11.8 – j11.0	7.8 – j10.4	15.0	59.3	15.4
3700	7.0 – j9.7	9.0 – j10.7	14.9	57.7	14.7
3800	4.2 – j11.4	9.1 – j11.5	14.6	57.9	15.0
Maximum	drain efficiency loa	d	,	<u> </u>	1
3300	11.1 – j22.0	4.8 – j5.6	11.3	62.8	17.7
3400	15.0 – j19.0	3.8 – j6.9	11.1	66.5	18.3
3500	15.2 – j13.0	3.1 – j8.2	10.1	68.4	18.9
3600	11.8 – j11.0	3.9 – j8.6	10.8	68.1	18.2
3700	7.0 – j9.7	4.0 – j9.8	10.6	66.1	17.2
3800	4.2 – j11.4	4.0 – j11.4	10.4	64.8	17.9

^[1] Z_S and Z_L defined in Figure 1.

[2] at 3 dB gain compression.

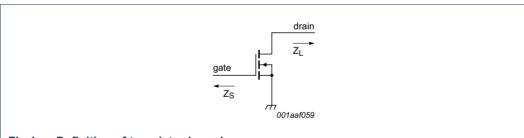


Fig 1. Definition of transistor impedance

7.3 Test circuit

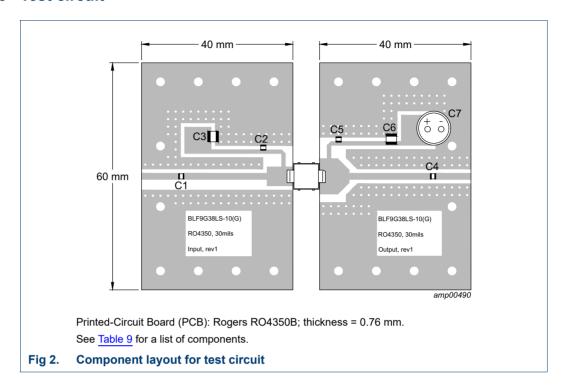
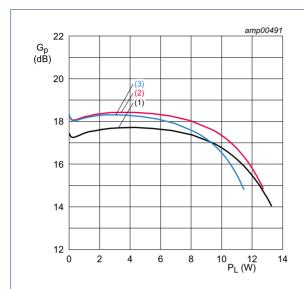


Table 9. List of components See Figure 2 for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	8.2 pF	ATC 100A
C2	multilayer ceramic chip capacitor	8.2 pF	ATC 100A
C3	multilayer ceramic chip capacitor	4.7 μF, 100 V	Murata
C4	multilayer ceramic chip capacitor	7.5 pF	ATC 100A
C5	multilayer ceramic chip capacitor	8.2 pF	ATC 100A
C6	multilayer ceramic chip capacitor	4.7 μF, 100 V	Murata
C7	electrolytic capacitor	220 μF	

7.4 Graphical data

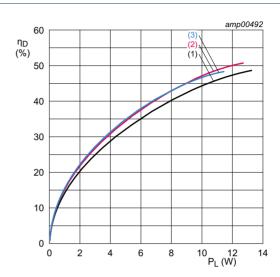
7.4.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 70 mA; t_p = 100 μ s; δ = 10 %.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 3. Power gain as a function of output power; typical values

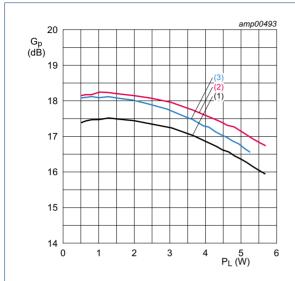


 V_{DS} = 28 V; I_{Dq} = 70 mA; t_p = 100 μ s; δ = 10 %.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 4. Drain efficiency as a function of output power; typical values

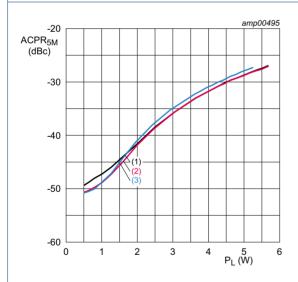
7.4.2 1-Carrier W-CDMA



 $V_{DS} = 28 \text{ V}; I_{Dq} = 70 \text{ mA}.$

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

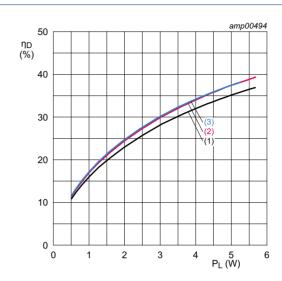
Fig 5. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 70 \text{ mA}.$

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

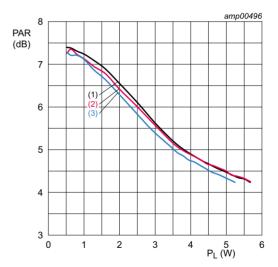
Fig 7. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 70 \text{ mA}.$

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 6. Drain efficiency as a function of output power; typical values

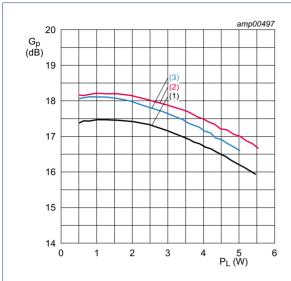


 $V_{DS} = 28 \text{ V}; I_{Dq} = 70 \text{ mA}.$

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 8. Peak-to-average ratio as a function of output power; typical values

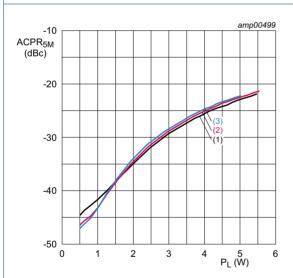
7.4.3 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 70 mA; 5 MHz spacing.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

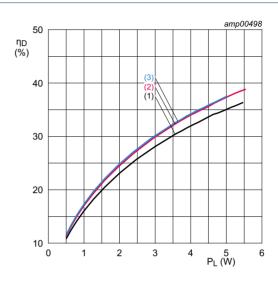
Fig 9. Power gain as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 70 mA; 5 MHz spacing.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

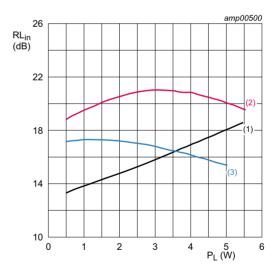
Fig 11. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 70 mA; 5 MHz spacing.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 10. Drain efficiency as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 70 mA; 5 MHz spacing.

- (1) f = 3405 MHz
- (2) f = 3500 MHz
- (3) f = 3595 MHz

Fig 12. Input return loss as a function of output power; typical values

8. Package outline

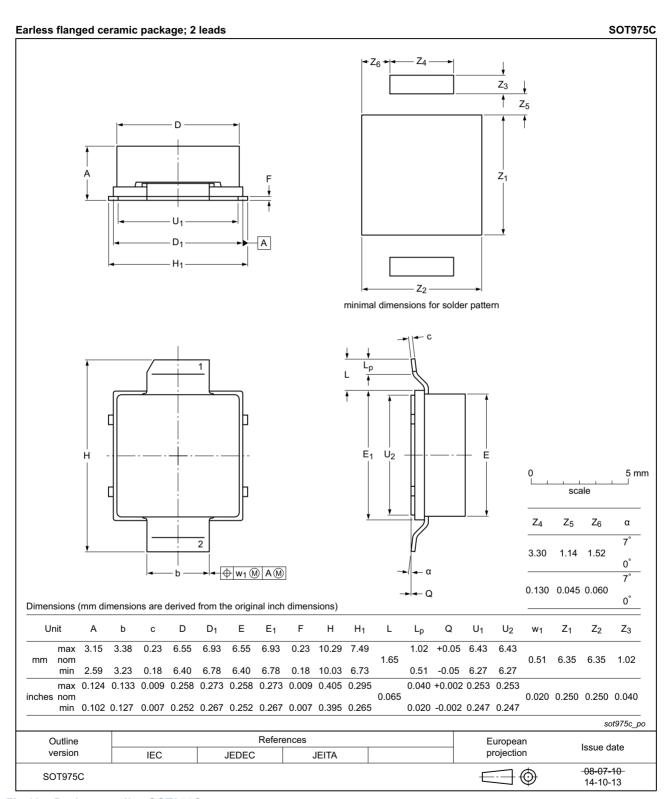


Fig 13. Package outline SOT975C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average power Ratio
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF9G38-10G v.1	20171019	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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